

# **DMN313DLT-7 Datasheet**



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DiGi Electronics Part Number

DMN313DLT-7-DG

Manufacturer

**Diodes Incorporated** 

Manufacturer Product Number

DMN313DLT-7

Description

MOSFET N-CH 30V 270MA SOT523

**Detailed Description** 

N-Channel 30 V 270mA (Ta) 280mW (Ta) Surface M

ount SOT-523



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# **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
DMN313DLT-7	Diodes Incorporated
Series:	Product Status:
	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
30 V	270mA (Ta)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
2.5V, 4.5V	20hm @ 10mA, 4V
Vgs(th) (Max) @ ld:	Gate Charge (Qg) (Max) @ Vgs:
1.5V @ 250µA	0.5 nC @ 4.5 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	36.3 pF @ 5 V
FET Feature:	Power Dissipation (Max):
	280mW (Ta)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Supplier Device Package:	Package / Case:
SOT-523	SOT-523
Base Product Number:	
DMN313	

# **Environmental & Export classification**

8541.21.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	





#### N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C
	2Ω @ V <sub>GS</sub> = 4V	270mA
30V	3.2Ω @ V <sub>GS</sub> = 2.5V	210mA

#### **Description and Applications**

This new generation MOSFET has been designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Backlighting
- DC-DC converters
- Power-management functions

#### **Features and Benefits**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Up to 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

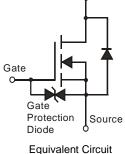
- Package: SOT523
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)

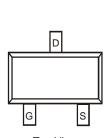
Drain





**SOT523** 





Top View

Top View Pin-Out

#### **Ordering Information** (Note 4)

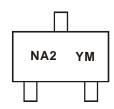
Part Number	Dackers	Packing		
Part Number	Package	Qty.	Carrier	
DMN313DLT-7	SOT523	3000	Tape & Reel	

Notes:

- 1. No purposely added lead, Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant,
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



# **Marking Information**



NA2 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: L = 2024) M = Month (ex: 9 = September)

Date Code Key

Year	2010		2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	Х		L	М	N	Р	R	S	T	U	V	W
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteri	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	30	V		
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 5) V <sub>GS</sub> = 4.0V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	0.27 0.21	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = 4.0V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	I <sub>D</sub>	0.31 0.25	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = 4.0V	t ≤ 10s	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	I <sub>D</sub>	0.38 0.3	А
Continuous Drain Current (Note 5) V <sub>GS</sub> = 2.5V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	0.21 0.15	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = 2.5V	ΙD	0.29 0.22	А		
Pulsed Drain Current (Note 7)			IDM	1.2	A

#### **Thermal Characteristics**

Characteristic	Symbol	Max	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	0.28	W
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 5)	Reja	474	°C/W
Power Dissipation (Note 6)	P <sub>D</sub>	0.36	W
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 6)	Reja	361	°C/W
Power Dissipation (Note 6) t ≤ 10s	PD	0.52	W
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 6) t ≤ 10s	Reja	252	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Notes:

- 5. Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.
- 6. Device mounted on 2" x 2" FR-4 PCB with high coverage 2 oz. Copper, single sided.
- 7. Repetitive rating, pulse width limited by junction temperature.

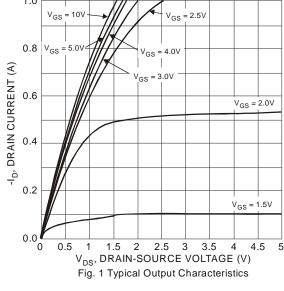


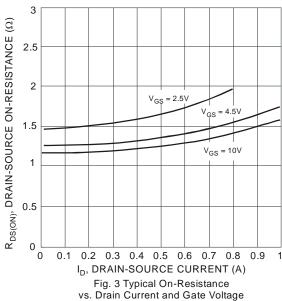
### Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

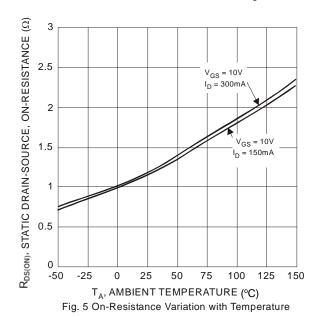
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						•
Drain-Source Breakdown Voltage	BVDSS	30	_	_	V	$V_{GS} = 0V, I_{D} = 250\mu A$
Zero Gate Voltage Drain Current, T <sub>J</sub> = +25°C	IDSS	_	_	0.1	μΑ	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±1.0	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.5	_	1.5	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$
Statia Drain Source On Registence	Dagger	_	1.3	2	Ω	$V_{GS} = 4V$ , $I_D = 10mA$
Static Drain-Source On-Resistance	RDS(ON)	_	1.6	3.2	Ω	$V_{GS} = 2.5V, I_{D} = 1mA$
Forward Transfer Admittance	Y <sub>FS</sub>	_	93	_	mS	$V_{DS} = 3V, I_{D} = 10mA$
Diode Forward Voltage	VsD	_	0.7	1.3	V	V <sub>G</sub> S = 0V, I <sub>S</sub> = 115mA
DYNAMIC CHARACTERISTICS (Note 9)	•					•
Input Capacitance	Ciss	_	36.3	_		
Output Capacitance	Coss	_	7.6	_	pF	$V_{DS} = 5V$ , $V_{GS} = 0V$ , $f = 1.0MHz$
Reverse Transfer Capacitance	C <sub>rss</sub>	_	4.7	_		I = 1.0IVIH2
Gate Resistance	Rg	_	128	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$
Total Gate Charge	Qg	_	0.5	_		
Gate-Source Charge	Qgs	_	0.1	_	nC	VGS = 4.5V, VDS = 15V,
Gate-Drain Charge	Qgd	_	0.1	_		$I_D = 10mA$
Turn-On Delay Time	t <sub>D(ON)</sub>	_	4.5	_	ns	
Turn-On Rise Time	t <sub>R</sub>	_	2.24	_	ns	V <sub>G</sub> S = 4.5V, V <sub>D</sub> S = 15V,
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	19.2	_	ns	$R_G = 2\Omega$ ,
Turn-Off Fall Time	tF	_	28.2	_	ns	I <sub>D</sub> = 180mA

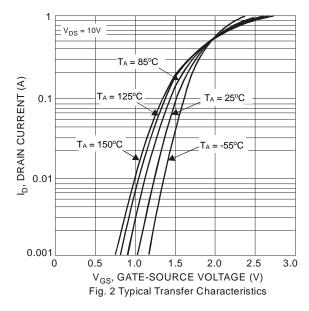
Notes:

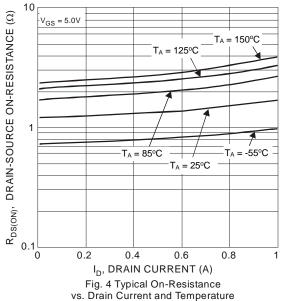
<sup>8.</sup> Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to production testing.











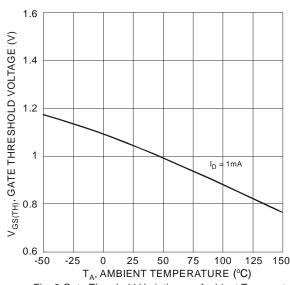
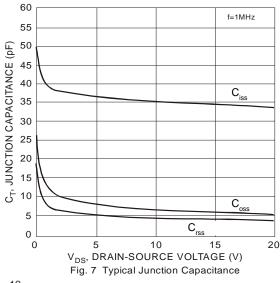
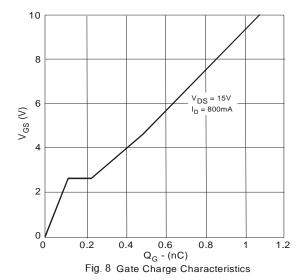
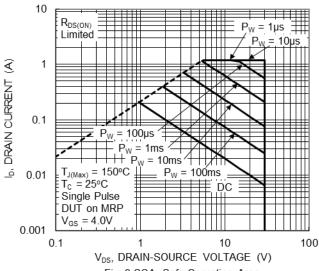


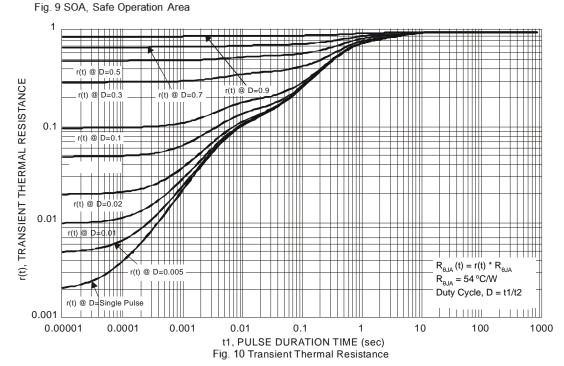
Fig. 6 Gate Threshold Variation vs. Ambient Temperature









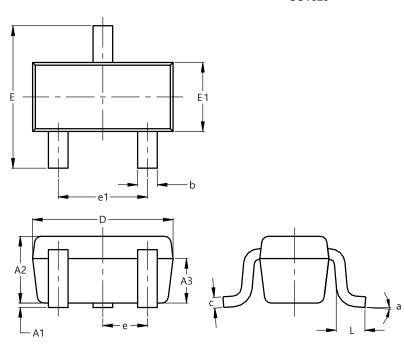




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT523

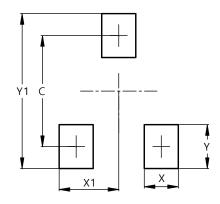


SOT523						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.60	0.80	0.75			
А3	0.45	0.65	0.50			
b	0.15	0.30	0.22			
С	0.10	0.20	0.12			
D	1.50	1.70	1.60			
Е	1.45	1.75	1.60			
E1	0.75	0.85	0.80			
е		0.50 BS	С			
e1	0.90	1.10	1.00			
L	0.20	0.40	0.33			
а	0°		8°			
Α	II Dimen	sions ir	n mm			

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT523**



Dimensions	Value (in mm)
С	1.29
Х	0.40
X1	0.70
Υ	0.51
Y1	1.80



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